

# Scintillation characteristics of an undoped CsI crystal at low-temperature for dark matter search

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**Abstract** The scintillation characteristics of an undoped CsI crystal with dimensions of 5.8 mm × 5.9 mm × 7.0 mm, corresponding to a weight of 1.0 g, were studied by directly coupling two silicon photomultipliers (SiPMs) over a temperature range from room temperature (300 K) to a low temperature of 86 K. The scintillation decay time and light output were measured using x-ray (23 keV) and gamma-ray (88 keV) peaks from a <sup>109</sup>Cd radioactive source. An increase in decay time was observed as the temperature decreased from room temperature to 86 K, ranging from 76 ns to 605 ns. Correspondingly, the light output increased as well, reaching  $37.9 \pm 1.5$  photoelectrons per keV electron-equivalent at 86 K, which is approximately 18 times higher than the light yield at room temperature. Leveraging the significantly enhanced scintillation light output of the undoped CsI crystal at the low temperature, coupling it with SiPMs makes it a promising candidate for the future dark matter search detector, benefiting from the low threshold owing to the high light output. The odd proton numbers from both cesium and iodine provide an advantage for the WIMP-proton spin-dependent interaction. We evaluated the sensitivity of low-mass dark matter on WIMP-proton spin-dependent interaction with the Migdal process, assuming 200 kg of undoped CsI crystals for the dark matter search. We conclude that undoped CsI crystal detectors exhibit world-competitive sensitivities for low-mass dark matter detection, particularly for the WIMP-proton spin-dependent interaction.

## 1 Introduction

The scintillation crystals are widely employed in the search for rare event interactions such as dark matter [1–4] or coherent elastic neutrino-nucleus scattering (CE $\nu$ NS) [5, 6]. Because of increased signals for both dark matter and neutrino interactions at low energies, low-threshold detectors are essential for dark matter or CE $\nu$ NS detection. In the case of scintillation detectors, the high light yield provides the necessary low-threshold detectors. The introduction of dopants during crystal growth, such as thallium in halide crystals (i.e., CsI(Tl) and NaI(Tl)), enhances radiative recombination and improves light emission efficiency. These doped crystals have been widely utilized at room temperature, coupled with photomultipliers, for dark matter and CE $\nu$ NS detection experiments [5–12]. The highest reported light yields from doped NaI(Tl) crystals were 22 photoelectrons/keV [6] with a novel crystal encapsulation technique [13]. There have been reports suggesting that undoped CsI and NaI crystals exhibit higher light yields at low temperatures [14–17]. At the liquid nitrogen temperature of 77 K, the undoped CsI crystal coupled with silicon photomultipliers (SiPMs) reported 43 photoelectrons/keV [18]. A similar setup, but introducing a wavelength shifter, resulted in an increased light yield of 52.1 photoelectrons/keV [19].

We investigate the scintillation characteristics of an undoped CsI crystal to assess their temperature-dependent behavior. To maximize the light collection of the undoped CsI crystal, two SiPMs are directly attached to the crystal. In a temperature range between 86 K and 293 K, we measure the light yield, scintillation decay time, and energy resolutions. Due to the exhibition of high dark count rates [20] and crosstalks [21, 22], we have carefully analyzed and corrected effects.

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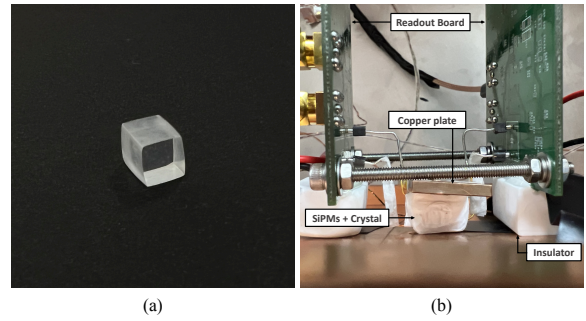
The low-background CsI crystal technique [23–25] has been developed for the KIMS experiment, which used CsI(Tl) crystals coupled with photomultipliers (PMTs) for WIMP dark matter search [26–28]. The production of 200 kg undoped CsI crystals can be performed at the Institute for Basic Science (IBS), Korea, with a powder purification facility [29–31] and Kyropoulos crystal growers [32], developed for low-background NaI(Tl) crystals [33, 34]. Additionally, about 400 kg of purified CsI powder remnants from the KIMS CsI(Tl) crystal growing have been stored at the Yangyang underground laboratory. Based on the high light yield of the undoped CsI crystals and the low-background CsI crystal growing technology, we evaluate the dark matter detection sensitivities of the future experiment using the undoped CsI crystals. In the low-mass dark matter region for the WIMP-proton spin-dependent interaction, the undoped CsI crystal can reach the world’s best sensitivities.

## 2 Scintillation characteristics of the undoped CsI crystal

### 2.1 Experimental setup

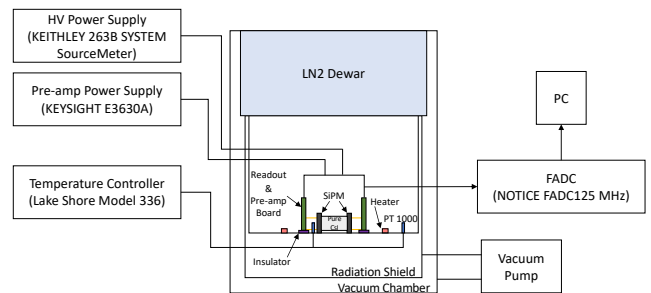
The detector assembly employed in this study comprises an undoped CsI crystal from the Institute for Scintillation Materials (ISMA) in Ukraine and two SiPMs from Hamamatsu Photonics. The undoped CsI crystal has dimensions of  $5.8 \text{ mm} \times 5.9 \text{ mm} \times 7.0 \text{ mm}$  with a mass of 1.0 g, as illustrated in Fig. 1 (a). Two SiPMs (model number S13360-2172) with an active area of  $6.0 \text{ mm} \times 6.0 \text{ mm}$  were directly attached to two ends of the crystal. This SiPM consists of 14,400 micropixel arrays, each of size  $50 \mu\text{m} \times 50 \mu\text{m}$ , covered with a quartz window. The entire assembly was tightly wrapped with soft polytetrafluoroethylene (PTFE) sheets and connected to homemade readout boards equipped with electronics for signal readout, pre-amplification, and bias voltage supply, as depicted in Fig. 1 (b).

The CsI-SiPMs setup was installed inside a cryostat vacuum chamber equipped with a temperature control unit, as depicted in Fig. 2. The liquid nitrogen dewar is connected to the copper plate through a thermal link composed of multiple copper wires. The CsI-SiPMs setup was mounted on the copper plate and covered with a radiation shield made of iron to protect against external radiation heat. Rubber insulators were introduced to prevent the conduction of heat from the readout board, as shown in Fig. 1 (b). To control the temperatures of the CsI crystal, two heaters were incorporated on the copper plate. Two PT-1000 temperature sensors were



**Fig. 1** (a) A  $5.8 \text{ mm} \times 5.9 \text{ mm} \times 7.0 \text{ mm}$  undoped CsI crystal is employed for the experiment. (b) The crystal is coupled with two SiPMs, enclosed with multiple layers of soft polytetrafluoroethylene (PTFE) sheets, and connected to readout boards. The entire assembly is placed inside a cryostat chamber.

employed to monitor the temperature inside the chamber using the temperature control unit of Lake Shore Model 336. One sensor was placed in close proximity to the crystal, while the other was positioned at the edge of the copper plate. The temperature control unit regulates the heater to manage temperature variations from the target temperature, maintaining a stability level of 0.1 degree. We optimized the power of the thermal connection between the nitrogen dewar and copper plate to achieve a minimum temperature closer to 77 K while ensuring efficient heat transfer to the crystal for increased temperatures. In this setup, we successfully reached a temperature of 86 K with both SiPMs and readout boards in operation.



**Fig. 2** Schematic drawing of the experimental setup.

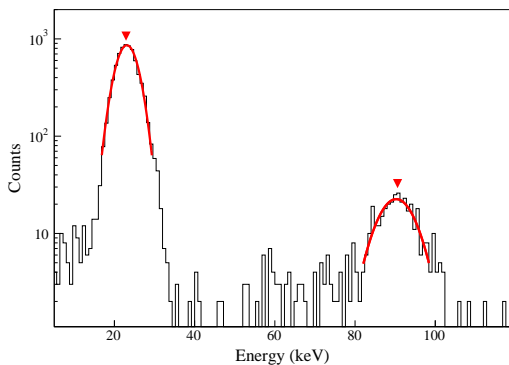
A KEITHLEY 263B SYSTEM SourceMeter is employed to provide the SiPM bias voltage through the readout boards, which are operated with a low-voltage supply using a KEYSIGHT E3630A. The readout electronics amplify the SiPM signals, and the amplified signals are digitized using a 125 MHz, 12-bit flash-analog-to-digital converter (FADC) supplied by NOTICE Korea.

## 2.2 Measurements

The performance of the SiPM is affected by the overvoltage, defined as  $\Delta V = V_{bias} - V_{breakdown}$ , where  $V_{breakdown}$  is the breakdown voltage. Data were collected using six different overvoltages ranging from 3 V to 8 V, with a 1 V interval at room temperature. The gain, represented by the height of a single photoelectron, was evaluated at each overvoltage. Since the photo detection efficiency (PDE) of SiPM varies with gain or overvoltage [35–41], we maintained a consistent overvoltage for the temperature-dependent measurements.

The temperature range for detector testing spanned from 86 K to 293 K (room temperature). Due to the limitations of the present setup, complete elimination of heat from the readout board was not achievable, resulting in a minimum temperature of 86 K, which is above the temperature of liquid nitrogen.

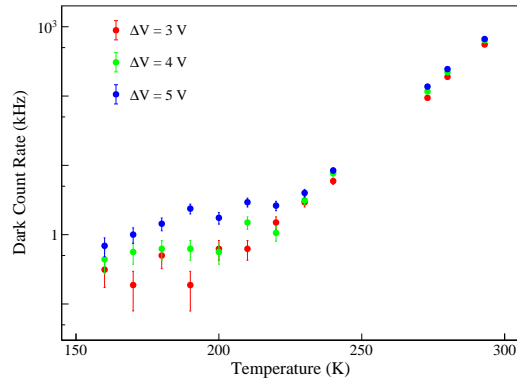
We characterized the scintillation characteristics of the undoped CsI crystal using a  $^{109}\text{Cd}$  source that emits 22.1 keV and 25.0 keV x-rays as well as an 88 keV  $\gamma$ -ray. Because of the energy resolution, the 22.1 keV and 25.0 keV x-rays overlapped and were roughly adjusted to around 23 keV, as shown in Fig. 3. All energy calibrations were performed with the 88 keV position, but the 23 keV peak is used to correct the relative charge for the 88 keV in case of low-temperature measurements.



**Fig. 3** The gamma energy spectrum from the  $^{109}\text{Cd}$  radioactive source measured at 150 K with  $\Delta V = 5$  V is presented. Red triangles mark the two energy peaks at 23 and 88 keV.

### 2.2.1 Dark Count Rate & Crosstalk

Two critical factors in understanding SiPM data are the dark count rate (DCR) and crosstalk. We estimated the DCR and crosstalk from the scintillation data, which were calculated within a  $1.6 \mu\text{s}$  time window prior to the event-triggered position. This time window was chosen



**Fig. 4** Dark count rate as a function of temperature for three different overvoltages.

to exclude contributions from the scintillation event itself or SiPM after-pulses.

The DCR is a significant noise source, particularly at room temperature, while it decreases significantly at lower temperatures [21]. Since the DCR depends on both temperature and bias voltage, we assessed the DCR by varying temperature and overvoltage, as shown in Fig. 4. The DCR increases with higher overvoltage and exhibits a dramatic decrease at lower temperatures. For instance, at room temperature, the DCR is about 700 kHz with  $\Delta V = 5$  V and decreased to 0.2 kHz at 160 K.

Crosstalk refers to the probability of an electron in one pixel with photon heat triggering another pixel, resulting in multiple photoelectron events. Crosstalk is independent of temperature variation but highly dependent on bias voltage [21, 22]. We evaluate the crosstalk probability at room temperature by varying overvoltage, as summarized in Table 1. In the calculation of the light yield, we have accounted for effects from the DCR and crosstalk.

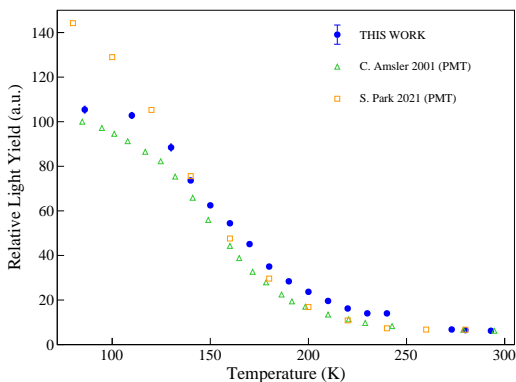
**Table 1** Crosstalk probability of SiPM measured at different overvoltages at room temperature.

Overvoltage (V)	Channel 1 (%)	Channel 2 (%)
3	$11.9 \pm 0.2$	$11.9 \pm 0.2$
4	$14.4 \pm 0.2$	$13.4 \pm 0.2$
5	$27.7 \pm 0.2$	$26.9 \pm 0.2$
6	$45.5 \pm 0.2$	$63.4 \pm 0.3$
7	$68.5 \pm 0.9$	$73.9 \pm 2.1$
8	$99.0 \pm 2.8$	$82.5 \pm 6.7$

### 2.2.2 Light Yield & Energy resolution

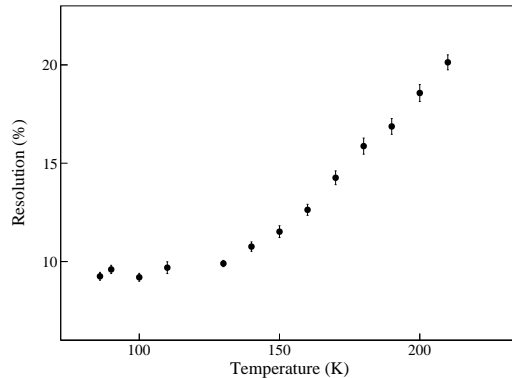
We measured the light yield of the undoped CsI crystal with the  $^{109}\text{Cd}$  source for temperatures ranging from 86 K to 293 K. To maintain a similar gain for different temperatures, we kept  $\Delta V = 5$  V, and the results are presented in Fig. 5. As shown in Fig. 5, the measured light yield of the undoped CsI crystal increased with decreasing temperature, consistent with previous measurements using typical PMTs [14, 15]. At the lowest temperature of 86 K with  $\Delta V = 8$  V, we obtained the highest light yield of  $37.9 \pm 1.5$  photoelectrons per keV, which is approximately 18 times larger than the light yield at room temperature. The contributions from DCR and crosstalk are considered in the light yield estimation, and the errors associated with these values are included as systematic uncertainties.

The emission wavelength of the undoped CsI crystal is peaked at 310 nm at room temperature and increased to 340 nm at 77 K [42]. At these wavelength, SiPMs have an almost twice higher PDE of roughly 30% than that of typical PMTs, which have a PDE of less than 15%. This results in an increased light yield compared to PMT measurements [43]. Similar increases with SiPMs coupled with undoped CsI crystals were observed by other groups [18], reporting 43.0 photoelectrons per keV at 77 K. Applying a wavelength shifter from 340 nm to 420 nm resulted in a further increase in light yield to 52.1 photoelectrons/keV [19].



**Fig. 5** Relative light yield of CsI as a function of temperature, with two previous measurements using PMT overlaid together for comparison [14, 15].

We estimated the root mean square (RMS) of the mixed 23 keV peak with a Gaussian fit to evaluate the resolution, calculated as RMS divided by energy. As shown in Fig 6, improved resolution at low temperatures is observed due to the increased light output.



**Fig. 6** Energy resolution (RMS/Energy) of 23 keV mixed peak from 22.1 keV and 25.0 keV x-rays of the  $^{109}\text{Cd}$  source at different temperatures with  $\Delta V = 5$  V.

### 2.2.3 Decay Time

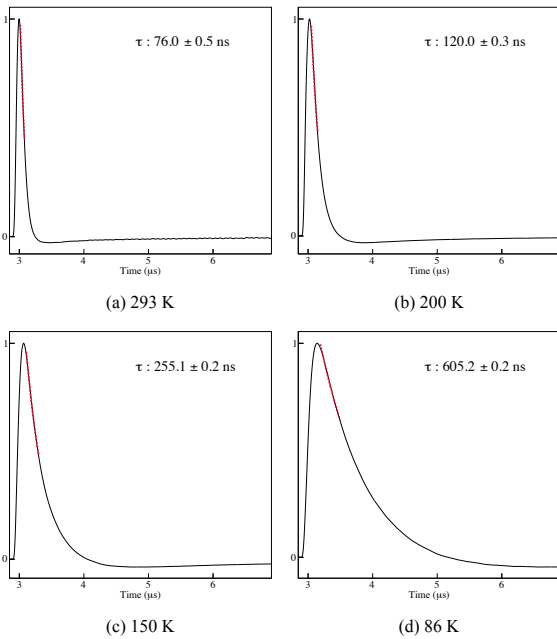
We investigated the temperature-dependent variation of the scintillation decay time of the undoped CsI crystal. The accumulated waveforms at each temperature were fitted with a single exponential function.

$$f(t) = A \exp(-(t - t_0)/\tau)$$

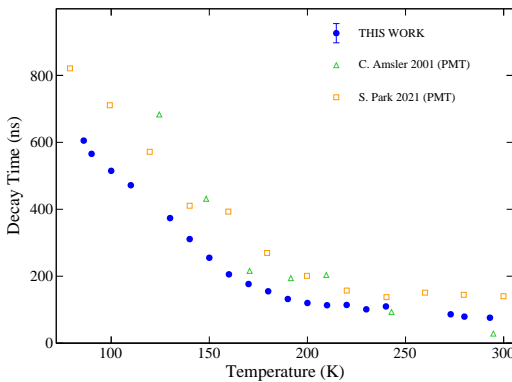
where  $\tau$  is the decay constant.  $A$  and  $t_0$  represent the normalization factor and the rising edge position of the scintillation, respectively.

The waveforms and fitted results for the four selected temperatures, presented in Fig. 7, revealed an undesired undershoot in the signal generated by our SiPM read-out electronics. To mitigate the potential misestimation of decay time caused by this undershoot, especially in the later part of the signal where long decay components may contribute, we performed the waveform fitting within a relatively short time range using a single exponential, despite previous PMT measurements indicating the presence of two decay components [14, 15].

The temperature-dependent decay time of the undoped CsI crystal is shown in Fig. 8 and compared with previous PMT measurements [14, 15]. Our measurements demonstrate a well-agreed trend of increased decay time at low temperatures. Slightly faster decay times in our measurements at all temperatures result from evaluating the decay time within a short time range, influenced by the severe undershoot discussed in the preceding paragraph. The measured decay time is  $76.0 \pm 0.5$  ns at room temperature and  $605.2 \pm 0.2$  ns at 86 K. Generally, a longer decay time is advantageous for identifying nuclear recoil events using pulse shape discrimination (PSD). We plan to measure PSD capability with a neutron source at liquid nitrogen temperatures later.



**Fig. 7** Accumulated waveforms of the 23 keV peak from  $^{109}\text{Cd}$  are shown at temperatures of 293 K, 200 K, 150 K, and 86 K, depicted in panels (a) to (d). The red dashed line represents the fitted exponential function, and the decay constant is described in each plot.



**Fig. 8** The decay time of a pure CsI crystal as a function of temperature is shown, with two previous measurements using PMTs overlaid for comparison [14, 15].

### 3 200 kg undoped CsI crystals for the dark matter search

Following up on the high light yield of the undoped CsI crystal at liquid nitrogen temperature, we consider future dark matter search experiments with 200 kg of undoped CsI crystals coupled with SiPM arrays, especially for low-mass dark matter with spin-dependent interactions. Both cesium and iodine have non-zero proton spin due to their odd proton numbers, providing an ad-

vantage for searching for WIMP-proton spin-dependent interactions.

The low-background CsI crystal growing technique was successfully developed for the KIMS CsI(Tl) dark matter search experiments [23, 44]. The primary sources of internal background in CsI crystals were identified as  $^{137}\text{Cs}$  and  $^{87}\text{Rb}$ . The presence of  $^{137}\text{Cs}$  is mainly attributed to water used in the chemical process of cesium extraction. By employing purified water, the contamination of  $^{137}\text{Cs}$  can be reduced by one order of magnitude in the CsI powder [24]. The  $^{87}\text{Rb}$  nuclei are extracted using the recrystallization method, taking advantage of the different solubility of RbI and CsI in water [44]. About 400 kg of remnant CsI powder, left over from the KIMS CsI(Tl) crystal growth process, has been stored at the Yangyang underground laboratory for 20 years. This reserve can be effectively utilized to grow 200 kg of undoped CsI crystals for future experiments. Additionally, a powder purification facility based on the recrystallization process was developed for NaI powder [29–31]. The adaptability of this facility for CsI powder purification is feasible, providing a streamlined process for maintaining low background levels in the CsI crystals if required.

Low-background crystal growing can be conducted at the Institute for Basic Science in Korea, where crystal growers have been developed for low-background NaI(Tl) crystals. The Kyropoulos growers designed for NaI(Tl) crystals can be readily adapted for undoped CsI crystal growth. Additionally, Brizman growers, commonly used for CsI crystal growth, are available for this purpose. In the KIMS experiment, the lowest background achieved at 2 keV was about 2.5 counts/kg/keV/day with the latest crystal delivered from Beijing Hamamatsu [45]. The radioactive background in the PMTs and the direct attachment of PMTs to the crystal contribute to external background at low energy, estimated to be approximately 0.5–1 counts/kg/keV/day [25]. Replacing the PMTs with SiPM arrays significantly reduces the external background contribution. Indeed, the contributions from  $^{134}\text{Cs}$ , estimated at the level of 1.0 count/kg/keV/day, can be considered negligible if crystals are grown using 20 years of underground-stored powder. This is attributed to the relatively short half-life of  $^{134}\text{Cs}$ , which is only 2.1 years. By leveraging existing powder and employing low-background crystal growing technology, the combination of undoped CsI crystals with SiPM arrays has the potential to achieve a background level of less than 1 count/kg/keV/day.

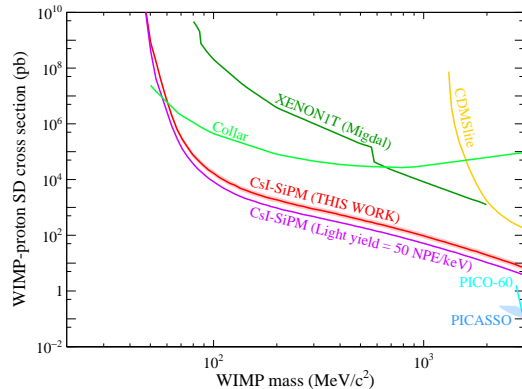
We are using a conservative estimate of 37.9 NPE/keV for light yields with the SiPM arrays, even though there is an around 10% increase in light output at 77 K compared to 86 K. In the low-energy data acquisition setup, where two SiPM arrays are attached to two ends of

the crystal, we can impose a requirement for coincident photoelectrons in the two SiPM arrays, corresponding to an energy threshold of roughly 0.05 keV. In contrast to PMT measurements, where PMT-induced noise from Cherenkov radiation of charged particles passing through quartz or glass materials can dominate low-energy events and increase the analysis threshold [46], such noise is less frequent in SiPM arrays since quartz or glass materials can be minimized in their construction. While DCR could be a potential concern, they are sufficiently low at 77 K. For the purpose of calculating dark matter detection sensitivities, we assume a 5 NPE threshold, consistent with CsI(Na) measurements using PMT readout [5].

The proposed 200 kg undoped CsI experiment can be implemented using a  $5 \times 5$  array of 8.7 kg CsI modules, each having dimensions of  $8 \text{ cm} \times 8 \text{ cm} \times 30 \text{ cm}$  (similar to the size used in the KIMS experiment [27, 28]). The two ends of the  $8 \text{ cm} \times 8 \text{ cm}$  side can be covered with  $13 \times 13$  SiPM arrays with  $6 \text{ mm} \times 6 \text{ mm}$  cells. The assumed parameters for the analysis include a flat background of 1 count/kg/keV/day, a light yield of 37.9 NPE/keV, and an analysis threshold of 5 NPE, corresponding to 0.05 keV. Additionally, an increased light yield of 50 NPE/keV, achieved through the application of a wavelength shifter [19], corresponding to a 0.04 keV threshold, is considered in the evaluation. For the benchmark model of the low-mass dark matter search, low-energy signals via Migdal electrons [47, 48] induced by WIMP-proton spin-dependent interaction are assessed. The calculations follow the methodology outlined in Refs. [48, 49]. Assuming a one-year data exposure with 200 kg of undoped CsI crystals, the Poisson fluctuation of the measured Number of Photoelectrons (NPE) is taken into account for the detector resolution, as discussed in Ref. [50]. The nuclear recoil quenching factors (QFs) which is the ratio of the scintillation light yield from cesium or iodine recoil relative to that from electron recoil for the same energy are additionally considered. The measured quenching factor of undoped CsI from Ref. [51] is incorporated into the calculations.

We use an ensemble of simulated experiments to estimate the sensitivity of the experiment. This ensemble test quantifies the expected cross-section limits for WIMP-proton spin-dependent interactions with the Migdal effect. For each experiment, we determine a simulated spectrum based on a background-only hypothesis with the assumed background. The simulated data is then fitted using a signal and background hypothesis. The fit is performed within the energy range of 5 NPE to 400 NPE for each WIMP model with varying masses, employing the Bayesian approach. The  $1\sigma$  and  $2\sigma$  standard-deviation probability regions of the

expected 90% confidence level limits are calculated from 1000 simulated experiments.



**Fig. 9** The expected 90% confidence level limits for the undoped CsI with a 200 kg, 1-year exposure using the Migdal effect on the WIMP-proton spin-dependent cross-section are presented, assuming the background-only hypothesis. In addition to the nominal assumed light yield of 37.9 NPE/keV, higher light yields, assuming the application of the wavelength shifter of 50 NPE/keV, are evaluated. These limits are compared with the current best limits from XENON1T (Migdal)[52], Collar[53], CDMSlite [54], PICO-60 [55], and PICASSO [56].

The limits on the WIMP-proton spin-dependent interaction with the Migdal effect shown in Fig. 9 are compared with the current best limits on the low-mass WIMP searches from XENON1T with Migdal[52], Collar [53], CDMSlite [54], PICO-60 [55], and PICASSO [56]. Taking advantage of odd-proton numbers and low-energy threshold, the projected sensitivity with 200 kg of undoped CsI experiment can reach the world's best sensitivities for WIMP masses between  $60 \text{ MeV}/c^2$  and  $2 \text{ GeV}/c^2$ .

## 4 Conclusion

The characteristics of a pure CsI crystal coupled with two SiPMs were investigated at temperatures ranging from 86 K to room temperature. The increased light yield and decay time at low temperatures were observed consistently with the literature. We obtained a light yield of  $37.9 \pm 1.5$  photoelectrons per keV at 86 K, which is 18 times larger than the light yield at room temperature. We investigated the expected sensitivities of the 200 kg undoped CsI experiment operated at 77 K with a 1-year period of operation, 1 count/kg/keV/day background rate, and a 5 NPE energy threshold. In this scenario, the undoped CsI crystal can explore low-mass dark matter of  $60 \text{ MeV}/c^2$  and  $2 \text{ GeV}/c^2$  with

the world's best sensitivities for WIMP-proton spin-dependent interactions.

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